Ce:GAGG cerium doped gadolinium aluminum gallium garnet：

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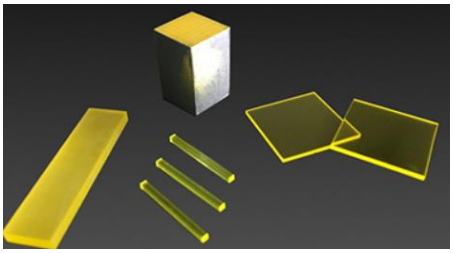

Ce:GAGG cerium-doped gadolinium aluminum gallium garnet is a relatively new single crystal scintillator with many properties such as high light yield, high density, good energy resolution, emission peaks well matched to silicon sensors, low Intrinsic Energy Resolution.

Main features:

High light output

high energy resolution

high density

no self-radiation

No deliquescence

Typical application:

Computed tomography (CT), positron emission tomography (PET), single photon emission computerized tomography (SPECT), particle accelerators, X-ray and gamma-ray detection, nuclear radiation sensing, industrial security inspection, high-energy physics and other fields .

Material properties:

molecular formula	Ce:$Gd_3Al_2Ga_3O_{12}$
density	6.63g/ cm3
hardness	8 Mohs
melting point	1850°C
atomic number	54.4
growth method	Czochralski
Thermal expansion coefficient	TBA* 10-6

Product parameters:

Orientation accuracy	<0.5°
size	Customized
tolerance	±0.05mm
Parallelism	＜30″
Perpendicularity	<15'
smoothness	10-5
Clear aperture	>90%
Chamfer	＜0.1mm @45°